74AHC138; 74AHCT138

3-to-8 line decoder/demultiplexer; inverting

Rev. 4 — 2 April 2014

Product data sheet

1. General description

The 74AHC138; 74AHCT138 are high-speed Si-gate CMOS devices and are pin compatible with Low power Schottky TTL (LSTTL). They are specified in compliance with JEDEC standard No. 7A.

The 74AHC138; 74AHCT138 is a 3-to-8 line decoder/demultiplexer. It accepts three binary weighted address inputs (A0, A1 and A2) and, when enabled, provides eight mutually exclusive outputs (\overline{Y} 0 to \overline{Y} 7) that are LOW when selected.

There are three enable inputs: two active LOW ($\overline{E}1$ and $\overline{E}2$) and one active HIGH (E3). Every output will be HIGH unless $\overline{E}1$ and $\overline{E}2$ are LOW and E3 is HIGH.

This multiple enable function allows easy parallel expansion of the device to a 1-of-32 (5 lines to 32 lines) decoder with just four 74AHC138; 74AHCT138 devices and one inverter. The 74AHC138; 74AHCT138 can be used as an eight output demultiplexer by using one of the active LOW enable inputs as the data input and the remaining enable inputs as strobes. Unused enable inputs must be permanently tied to their appropriate active HIGH or LOW state.

2. Features and benefits

- Balanced propagation delays
- All inputs have Schmitt-trigger action
- Demultiplexing capability
- Multiple input enable for easy expansion
- Ideal for memory chip select decoding
- Inputs accepts voltages higher than V_{CC}
- For 74AHC138 only: operates with CMOS input levels
- For 74AHCT138 only: operates with TTL input levels
- ESD protection:
 - ◆ HBM JESD22-A114E exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
 - ◆ CDM JESD22-C101C exceeds 1000 V
- Multiple package options
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

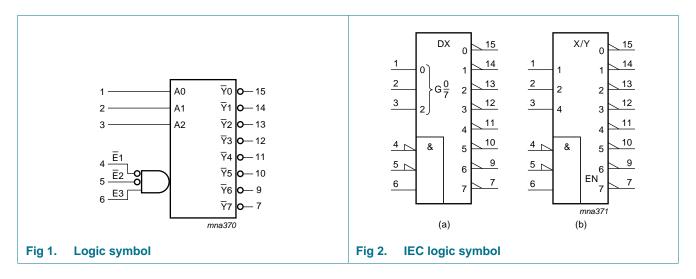


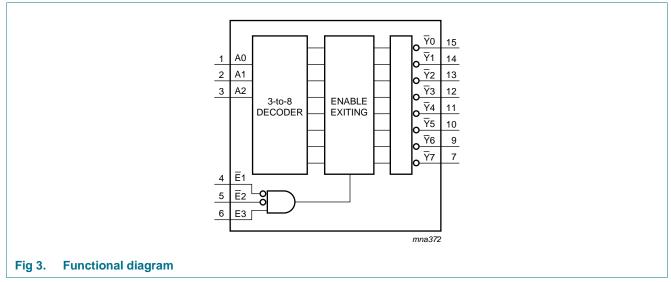
3. Ordering information

Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74AHC138D	–40 °C to +125 °C	SO16	plastic small outline package; 16 leads;	SOT109-1
74AHCT138D			body width 3.9 mm	
74AHC138PW	−40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads;	SOT403-1
74AHCT138PW	_		body width 4.4 mm	
74AHC138BQ	−40 °C to +125 °C	DHVQFN16	plastic dual in-line compatible thermal-enhanced very	SOT763-1
74AHCT138BQ	-		thin quad flat package; no leads; 16 terminals; body $2.5 \times 3.5 \times 0.85$ mm	

4. Functional diagram

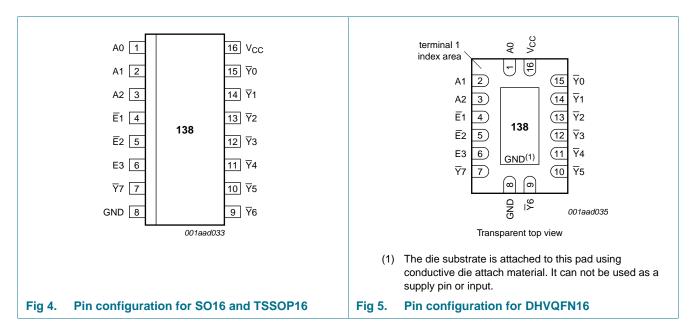




74AHC_AHCT138

5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
A0	1	address input
A1	2	address input
A2	3	address input
E 1	4	enable input (active LOW)
E 2	5	enable input (active LOW)
E3	6	enable input (active HIGH)
GND	8	ground (0 V)
\overline{Y} 0 to \overline{Y} 7	15, 14, 13, 12, 11, 10, 9, 7	output
V _{CC}	16	supply voltage

6. Functional description

Table 3. Function table [1]

Input						Output									
E1	<u>E</u> 2	E3	A0	A1	A2	<u>Y</u> 0	<u>Y</u> 1	<u>Y</u> 2	Y 3	<u>Y</u> 4	<u>Y</u> 5	Y 6	Y 7		
Н	Х	Х	X	Х	Х	Н	Н	Н	Н	Н	Н	Н	Н		
Χ	Н	Х	X	X	Х	Н	Н	Н	Н	Н	Н	Н	Н		
Χ	Х	L	Х	Х	Х	Н	Н	Н	Н	Н	Н	Н	Н		
L	L	Н	L	L	L	L	Н	Н	Н	Н	Н	Н	Н		
L	L	Н	Н	L	L	Н	L	Н	Н	Н	Н	Н	Н		
L	L	Н	L	Н	L	Н	Н	L	Н	Н	Н	Н	Н		
L	L	Н	Н	Н	L	Н	Н	Н	L	Н	Н	Н	Н		
L	L	Н	L	L	Н	Н	Н	Н	Н	L	Н	Н	Н		
L	L	Н	Н	L	Н	Н	Н	Н	Н	Н	L	Н	Н		
L	L	Н	L	Н	Н	Н	Н	Н	Н	Н	Н	L	Н		
L	L	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	L		

^[1] H = HIGH voltage level; L = LOW voltage level; X = don't care

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CC}	supply voltage			-0.5	+7.0	V
VI	input voltage			-0.5	+7.0	V
I _{IK}	input clamping current	V _I < -0.5 V	[1]	-20	-	mA
I _{OK}	output clamping current	$V_O < -0.5 \text{ V or } V_O > V_{CC} + 0.5 \text{ V}$	[1]	-	±20	mA
Io	output current	$V_{O} = -0.5 \text{ V to } (V_{CC} + 0.5 \text{ V})$		-	±25	mA
I _{CC}	supply current			-	75	mA
I _{GND}	ground current			-75	-	mA
T _{stg}	storage temperature			-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$				
	SO16 package		[2]	-	500	mW
	TSSOP16 package		[3]	-	500	mW
	DHVQFN16 package		[4]	-	500	mW

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

^[2] $\;\;$ P $_{tot}$ derates linearly with 8 mW/K above 70 °C.

^[3] P_{tot} derates linearly with 5.5 mW/K above 60 °C.

^[4] P_{tot} derates linearly with 4.5 mW/K above 60 °C.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	74AH	C138		74AH	74AHCT138			
			Min	Тур	Max	Min	Тур	Max		
V _{CC}	supply voltage		2.0	5.0	5.5	4.5	5.0	5.5	V	
VI	input voltage		0	-	5.5	0	-	5.5	V	
Vo	output voltage		0	-	V _{CC}	0	-	V _{CC}	V	
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C	
	input transition rise	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$	-	-	100	-	-	-	ns/V	
	and fall rate	$V_{CC} = 5.0 \text{ V} \pm 0.5 \text{ V}$	-	-	20	-	-	20	ns/V	

9. Static characteristics

Table 6. Static characteristics

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		-40 °C	to +85 °C	-40 °C 1	Unit	
			Min	Тур	Max	Min	Max	Min	Max	
For type	74AHC138									
V _{IH}	HIGH-level	$V_{CC} = 2.0 \text{ V}$	1.5	-	-	1.5	-	1.5	-	V
	input voltage	V _{CC} = 3.0 V	2.1	-	-	2.1	-	2.1	-	V
		V _{CC} = 5.5 V	3.85	-	-	3.85	-	3.85	-	V
V_{IL}	LOW-level	V _{CC} = 2.0 V	-	-	0.5	-	0.5	-	0.5	V
	input voltage	V _{CC} = 3.0 V	-	-	0.9	-	0.9	-	0.9	V
		V _{CC} = 5.5 V	-	-	1.65	-	1.65	-	1.65	V
V _{OH}	HIGH-level	$V_I = V_{IH}$ or V_{IL}								
	output voltage	$I_{O} = -50 \mu A; V_{CC} = 2.0 V$	1.9	2.0	-	1.9	-	1.9	-	V
		$I_O = -50 \mu A; V_{CC} = 3.0 \text{ V}$	2.9	3.0	-	2.9	-	2.9	-	V
		$I_O = -50 \mu A; V_{CC} = 4.5 V$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_O = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.58	-	-	2.48	-	2.4	-	V
		$I_{O} = -8.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.94	-	-	3.8	-	3.7	-	V
V_{OL}	LOW-level	$V_I = V_{IH}$ or V_{IL}								
	output voltage	$I_O = 50 \mu A; V_{CC} = 2.0 V$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 50 \mu A; V_{CC} = 3.0 V$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 50 \mu A; V_{CC} = 4.5 V$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.36	-	0.44	-	0.55	V
		$I_O = 8.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.36	-	0.44	-	0.55	V
Iı	input leakage current	V _I = 5.5 V or GND; V _{CC} = 0 V or 5.5 V	-	-	0.1	-	1.0	-	2.0	μА
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$	-	-	4.0	-	40	-	80	μА
C _I	input capacitance		-	3.0	10	-	10	-	10	pF

Table 6. Static characteristics ...continued Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		-40 °C	to +85 °C	-40 °C t	o +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
For type	74AHCT138									
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	-	-	2.0	-	2.0	-	V
V _{IL}	LOW-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	-	-	0.8	-	0.8	-	0.8	V
V _{OH} HIGH-level		$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$								
output voltage	I _O = -50 μA	4.4	4.5	-	4.4	-	4.4	-	V	
		$I_{O} = -8.0 \text{ mA}$	3.94	-	-	3.8	-	3.7	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$								
		I _O = 50 μA	-	0	0.1	-	0.1	-	0.1	V
		I _O = 8.0 mA	-	-	0.36	-	0.44	-	0.55	V
I _I	input leakage current	V _I = 5.5 V or GND; V _{CC} = 0 V or 5.5 V	-	-	0.1	-	1.0	-	2.0	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$	-	-	4.0	-	40	-	80	μΑ
Δl _{CC}	additional supply current	per input pin; $V_I = V_{CC} - 2.1 \text{ V}; I_O = 0 \text{ A};$ other pins at V_{CC} or GND; $V_{CC} = 4.5 \text{ V}$ to 5.5 V	-	-	1.35	-	1.5	-	1.5	mA
Cı	input capacitance		-	3.0	10	-	10	-	10	pF

10. Dynamic characteristics

Table 7. Dynamic characteristics

GND = 0 V; For test circuit see Figure 8.

Symbol	Parameter	Conditions		25 °C		-40 °C	to +85 °C	-40 °C 1	to +125 °C	Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	
For type	74AHC138									
t _{pd}	propagation	An to Yn; see Figure 6	1							
	delay	V _{CC} = 3.0 V to 3.6 V								
		C _L = 15 pF	-	6.0	11.4	1.0	13.0	1.0	14.5	ns
		C _L = 50 pF	-	8.6	15.8	1.0	18.0	1.0	20.0	ns
		V _{CC} = 4.5 V to 5.5 V								
		C _L = 15 pF	-	4.4	8.1	1.0	9.5	1.0	10.5	ns
		C _L = 50 pF	-	6.3	10.1	1.0	11.5	1.0	13.0	ns
		E3 to \overline{Y} n; see Figure 6	1							
		V _{CC} = 3.0 V to 3.6 V								
		C _L = 15 pF	-	5.8	12.8	1.0	15.0	1.0	16.0	ns
		C _L = 50 pF	-	8.2	16.3	1.0	18.5	1.0	20.5	ns
		V _{CC} = 4.5 V to 5.5 V								
		C _L = 15 pF	-	4.2	8.1	1.0	9.5	1.0	10.5	ns
		C _L = 50 pF	-	6.0	10.1	1.0	11.5	1.0	13.0	ns
		E1, E2 to Yn; see Figure 7	1							
		V _{CC} = 3.0 V to 3.6 V								
		C _L = 15 pF	-	5.7	11.4	1.0	13.5	1.0	14.5	ns
		C _L = 50 pF	-	8.2	14.9	1.0	17.0	1.0	19.0	ns
		V _{CC} = 4.5 V to 5.5 V								
		C _L = 15 pF	-	4.2	8.1	1.0	9.5	1.0	10.5	ns
		C _L = 50 pF	-	6.0	10.1	1.0	11.5	1.0	13.0	ns
C _{PD}	power dissipation capacitance	$C_L = 50 \text{ pF}; f_i = 1 \text{ MHz};$ $V_I = \text{GND to } V_{CC}$	1 -	18.0	-	-	-	-	-	pF

Dynamic characteristics ...continued Table 7.

GND = 0 V; For test circuit see Figure 8.

Symbol	Parameter	Conditions		25 °C		-40 °C	to +85 °C	-40 °C t	o +125 °C	Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	
For type	74AHCT138									
t _{pd}	propagation	An to Yn; see Figure 6	2]							
	delay	V _{CC} = 4.5 V to 5.5 V								
		C _L = 15 pF	-	4.4	10.4	1.0	12.0	1.0	13.0	ns
		C _L = 50 pF	-	6.2	11.4	1.0	13.0	1.0	14.5	ns
		E3 to Yn; see Figure 6 [2]								
		V _{CC} = 4.5 V to 5.5 V								
		C _L = 15 pF	-	4.3	9.1	1.0	10.5	1.0	11.5	ns
		C _L = 50 pF	-	6.2	10.1	1.0	11.5	1.0	13.0	ns
		E1, E2 to Yn; see Figure 7	2]							
		V _{CC} = 4.5 V to 5.5 V								
		C _L = 15 pF	-	4.3	9.6	1.0	11.0	1.0	12.0	ns
		C _L = 50 pF	-	6.2	10.6	1.0	12.0	1.0	13.5	ns
C _{PD}	power dissipation capacitance	$C_L = 50 \text{ pF}; f_i = 1 \text{ MHz};$ $V_I = \text{GND to } V_{CC}$	4] -	23.0	-	-	-	-	-	pF

- [1] Typical values are measured at nominal supply voltage ($V_{CC} = 3.3 \text{ V}$ and $V_{CC} = 5.0 \text{ V}$).
- [2] t_{pd} is the same as t_{PLH} and t_{PHL} .
- [3] Skew between any two outputs of the same package switching in the same direction. This parameter is guaranteed by design.
- C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o) \text{ where:}$

 f_i = input frequency in MHz, f_o = output frequency in MHz

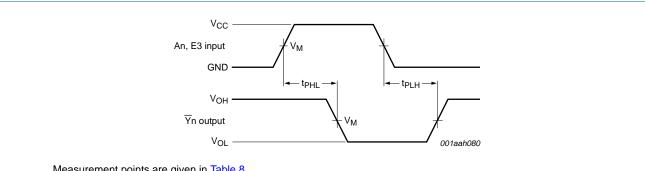
C_L = output load capacitance in pF

V_{CC} = supply voltage in V

N = number of inputs switching

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

11. Waveforms



Measurement points are given in Table 8.

V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

The inputs An, E3 to outputs Yn propagation delays Fig 6.

74AHC AHCT138

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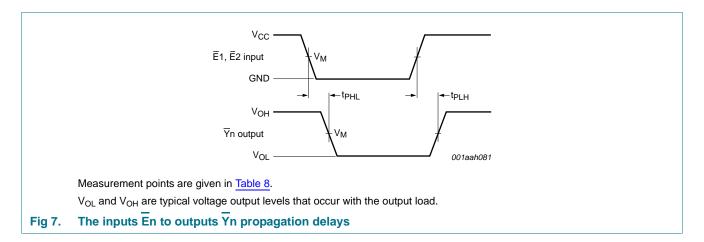
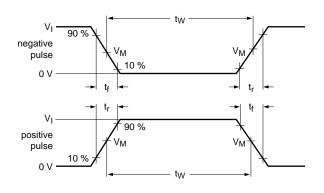
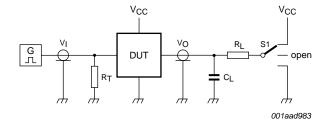


Table 8. Measurement points

Туре	Input	Output
	V _M	V _M
74AHC138	0.5V _{CC}	0.5V _{CC}
74AHCT138	1.5 V	0.5V _{CC}





Test data is given in Table 9.

Definitions test circuit:

 R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator.

 C_L = Load capacitance including jig and probe capacitance.

 R_L = Load resistance.

S1 = Test selection switch.

Fig 8. Load circuit for switching times

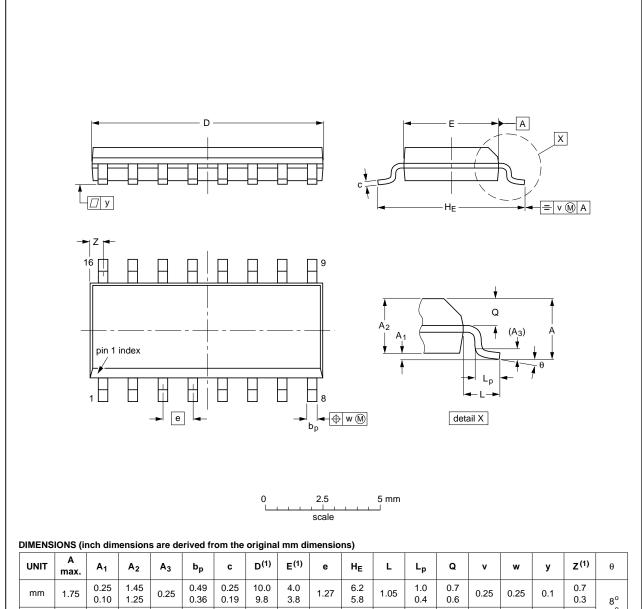
Table 9. Test data

Туре	Input		Load		S1 position				
	V_{I}	t _r , t _f	C _L R _L		t _{PHL} , t _{PLH}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}		
74AHC138	V_{CC}	≤ 3.0 ns	15 pF, 50 pF	1 kΩ	open	GND	V _{CC}		
74AHCT138	3.0 V	≤ 3.0 ns	15 pF, 50 pF	1 kΩ	open	GND	V _{CC}		

12. Package outline

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	ø	v	w	у	Z ⁽¹⁾	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	10.0 9.8	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.010 0.004	0.057 0.049	0.01		0.0100 0.0075		0.16 0.15	0.05	0.244 0.228	0.041	0.039 0.016		0.01	0.01	0.004	0.028 0.012	0°

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

			REFERENCES					
IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE			
076E07	MS-012				99-12-27 03-02-19			
					IEC JEDEC JEHA			

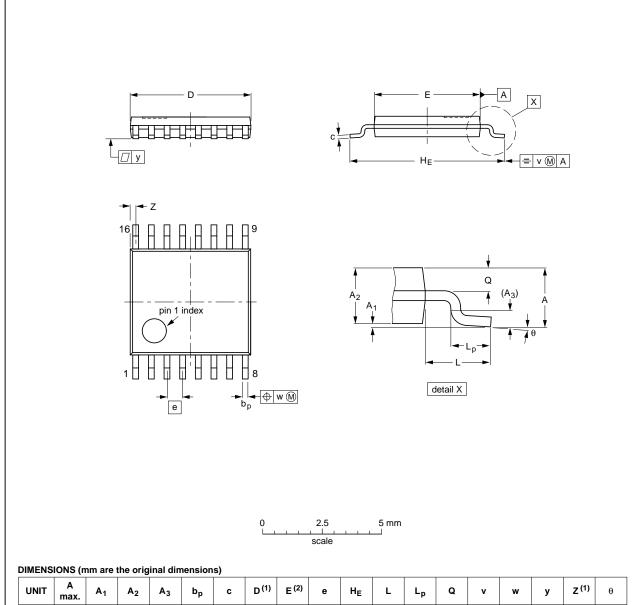
Package outline SOT109-1 (SO16) Fig 9.

74AHC_AHCT138

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TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



		,					~,												
UN	IT r	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E (2)	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mı	n	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.40 0.06	8° 0°

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

	OUTLINE		REFER	EUROPEAN	ISSUE DATE		
	VERSION	IEC	JEDEC	JEITA		PROJECTION	1330E DATE
	SOT403-1		MO-153				-99-12-27 03-02-18
-						'	

Fig 10. Package outline SOT403-1 (TSSOP16)

74AHC_AHCT138

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DHVQFN16: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 x 3.5 x 0.85 mm SOT763-1

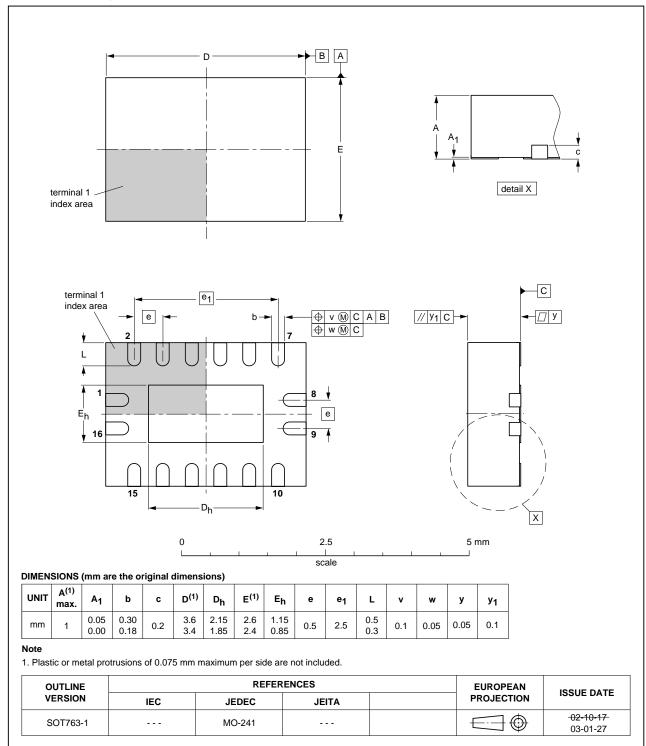


Fig 11. Package outline SOT763-1 (DHVQFN16)

74AHC_AHCT138

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13. Abbreviations

Table 10. Abbreviations

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
LSTTL	Low-power Schottky Transistor-Transistor Logic
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
CDM	Charged-Device Model
TTL	Transistor-Transistor Logic

14. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74AHC_AHCT138 v.4	20140402	Product data sheet	-	74AHC_AHCT138 v.3
Modifications:	 Description for t_{pd} for 	or the 74AHCT138 correct	ted (errata) in Table 7 "D	ynamic characteristics"
74AHC_AHCT138 v.3	20071128	Product data sheet	-	74AHC_AHCT138 v.2
74AHC_AHCT138 v.2	19990927	Product specification	-	74AHC_AHCT138 v.1
74AHC_AHCT138 v.1	19900331	Product specification	-	-

15. Legal information

15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

15.2 Definitions

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3-to-8 line decoder/demultiplexer; inverting

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